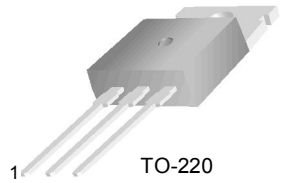


TIP47/TIP48/TIP49/TIP50

NPN Silicon Transistor

- High Voltage and Switching Applications
- High Sustaining Voltage : $V_{CEO(sus)} = 250 - 400V$
- 1A Rated Collector Current



1.Base 2.Collector 3.Emitter

Absolute Maximum Ratings* $T_a = 25^\circ C$ unless otherwise noted

Symbol	Parameter	Ratings	Units
V_{CBO}	Collector-Base Voltage : TIP47	350	V
	: TIP48	400	V
	: TIP49	450	V
	: TIP50	500	V
V_{CEO}	Collector-Emitter Voltage : TIP47	250	V
	: TIP48	300	V
	: TIP49	350	V
	: TIP50	400	V
V_{EBO}	Emitter-Base Voltage	5	V
I_C	Collector Current (DC)	1	A
I_{CP}	Collector Current (Pulse)	2	A
I_B	Base Current	0.6	A
P_C	Collector Dissipation ($T_C=25^\circ C$)	40	W
	Collector Dissipation ($T_a=25^\circ C$)	2	W
T_J	Junction Temperature	150	$^\circ C$
T_{STG}	Storage Temperature	- 65 ~ 150	$^\circ C$

* These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

Electrical Characteristics* $T_a=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
$V_{CEX(sus)}$	Collector-Emitter Sustaining Voltage	$I_C = 30\text{mA}, I_B = 0$	250			V
	: TIP47					
	: TIP48					
	: TIP49					
: TIP50						
I_{CEO}	Collector Cut-off Current	$V_{CE} = 150\text{V}, I_B = 0$			1	mA
	: TIP47	$V_{CE} = 200\text{V}, I_B = 0$			1	mA
	: TIP48	$V_{CE} = 250\text{V}, I_B = 0$			1	mA
	: TIP49	$V_{CE} = 300\text{V}, I_B = 0$			1	mA
I_{CEX}	Collector Cut-off Current	$V_{CE} = 350\text{V}, V_{BE} = 0$			1	mA
	: TIP47	$V_{CE} = 400\text{V}, V_{BE} = 0$			1	mA
	: TIP48	$V_{CE} = 450\text{V}, V_{BE} = 0$			1	mA
	: TIP49	$V_{CE} = 500\text{V}, V_{BE} = 0$			1	mA
I_{EBO}	Emitter Cut-off Current	$V_{EB} = 5\text{V}, I_C = 0$			1	mA
h_{FE}	* DC Current Gain	$V_{CE} = 10\text{V}, I_C = 0.3\text{A}$	30		150	
		$V_{CE} = 10\text{V}, I_C = 1\text{A}$	10			
$V_{CE(sat)}$	* Collector-Emitter Saturation Voltage	$I_C = 1\text{A}, I_B = 0.2\text{A}$			1	V
$V_{BE(sat)}$	* Base-Emitter Saturation Voltage	$V_{CE} = 10\text{V}, I_C = 1\text{A}$			1.5	V
f_T	Current Gain Bandwidth Product	$V_{CE} = 10\text{V}, I_C = 0.2\text{A}, f = 1\text{MHz}$	10			MHz

* Pulse Test: Pulse Width $\leq 300\mu\text{s}$, Duty Cycle $\leq 2\%$

Typical Characteristics

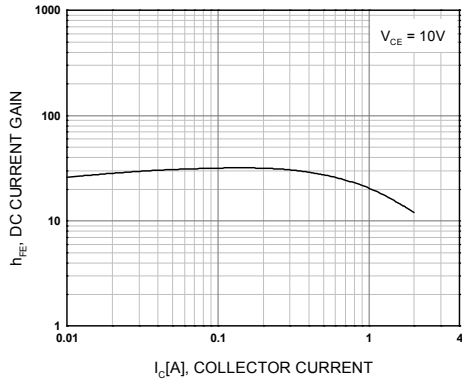


Figure 1. DC current Gain

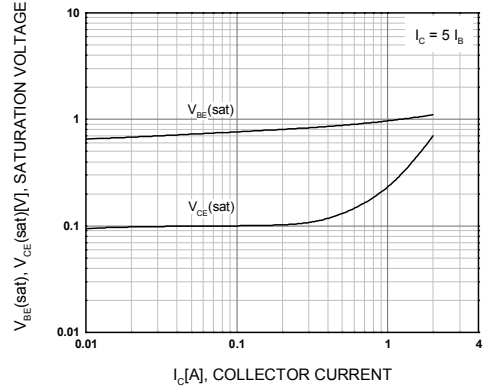


Figure 2. Collector-Emitter Saturation Voltage
Base-Emitter Saturation Voltage

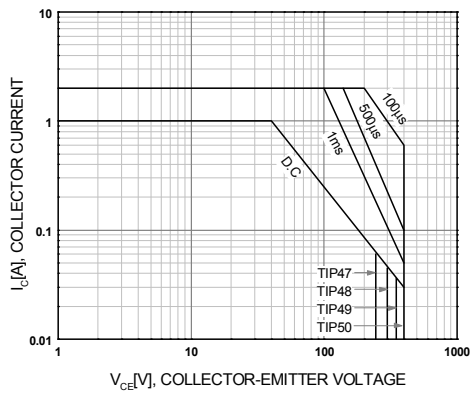


Figure 3. Safe Operating Area

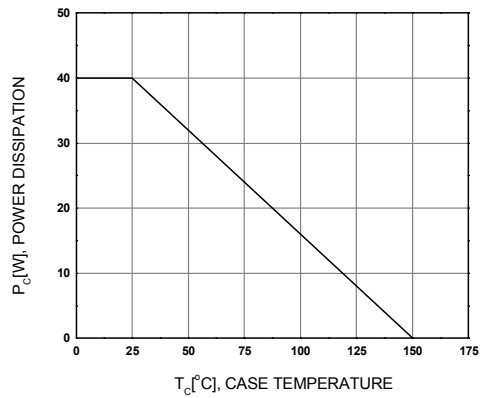
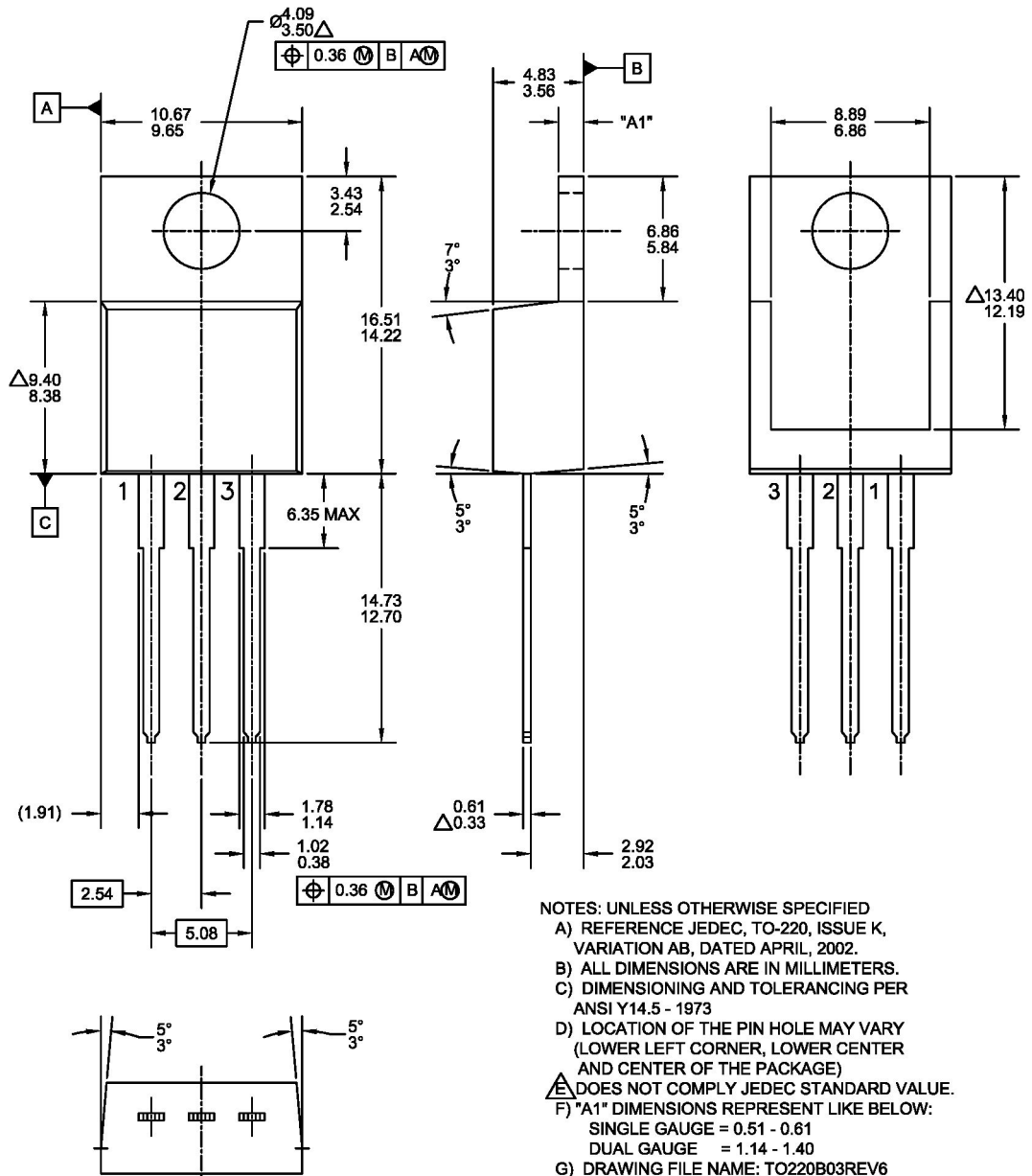


Figure 4. Power Derating

Mechanical Dimensions

TO220



- NOTES: UNLESS OTHERWISE SPECIFIED
 A) REFERENCE JEDEC, TO-220, ISSUE K, VARIATION AB, DATED APRIL, 2002.
 B) ALL DIMENSIONS ARE IN MILLIMETERS.
 C) DIMENSIONING AND TOLERANCING PER ANSI Y14.5 - 1973
 D) LOCATION OF THE PIN HOLE MAY VARY (LOWER LEFT CORNER, LOWER CENTER AND CENTER OF THE PACKAGE)
 E) DOES NOT COMPLY JEDEC STANDARD VALUE.
 F) "A1" DIMENSIONS REPRESENT LIKE BELOW:
 SINGLE GAUGE = 0.51 - 0.61
 DUAL GAUGE = 1.14 - 1.40
 G) DRAWING FILE NAME: TO220B03REV6



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Rev. I31



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